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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR NP32N055HDE, NP32N055IDE, NP32N055SDE

SWITCHING N-CHANNEL POWER MOSFET

DESCRIPTION

These products are N-channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

- Channel temperature 175 degree rated
- Super low on-state resistance
- $R_{DS(on)1}$ = 24 m Ω MAX. (V_{GS} = 10 V, I_D = 16 A)
- $R_{DS(on)2}$ = 29 m Ω MAX. (VGs = 5.0 V, ID = 16 A)
- Low Ciss : Ciss = 1300 pF TYP.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (VGS = 0 V)	VDSS	55	V
Gate to Source Voltage (V_{DS} = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	D(DC)	±32	А
Drain Current (pulse) Note1	D(pulse)	±100	А
Total Power Dissipation (Tc = 25°C)	P _{T1}	66	W
Total Power Dissipation (T _A = 25°C)	P _{T2}	1.2	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	-55 to +175	°C
Single Avalanche Current Note2	As	28 / 21 / 8	А
Single Avalanche Energy Note2	Eas	7.8 / 44 / 64	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V

THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	2.27	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	125	°C/W

***** ORDERING INFORMATION

PART NUMBER	PACKAGE		
NP32N055HDE	TO-251 (JEITA) / MP-3		
NP32N055IDE Note	TO-252 (JEITA) / MP-3Z		
NP32N055SDE	TO-252 (JEDEC) / MP-3ZK		

Note Not for new design.

(TO-251)

(TO-252)



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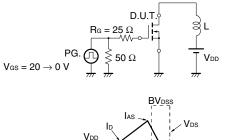
The mark \star shows major revised points.

ELECTRICAL CHARACTERISTICS (TA = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 55 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	Igss	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA
Gate to Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	1.5	2	2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = 10 V, I _D = 16 A	8	16		S
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = 10 V, I _D = 16 A		19	24	mΩ
	RDS(on)2	V _{GS} = 5.0 V, I _D = 16 A		22	29	mΩ
	RDS(on)3	V _{GS} = 4.5 V, I _D = 16 A		24	33	mΩ
Input Capacitance	Ciss	V _{DS} = 25 V		1300	2000	pF
Output Capacitance	Coss	V _{GS} = 0 V		180	270	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		90	160	pF
Turn-on Delay Time	td(on)	V _{DD} = 28 V, I _D = 16 A		14	31	ns
Rise Time	tr	V _{GS} = 10 V		8	20	ns
Turn-off Delay Time	td(off)	R _G = 1 Ω		40	81	ns
Fall Time	tr			7.4	19	ns
Total Gate Charge	Q _{G1}	V _{DD} = 44 V, V _{GS} = 10 V, I _D = 32 A		27	41	nC
	Q _{G2}	V _{DD} = 44 V		15	23	nC
Gate to Source Charge	QGS	V _{GS} = 5.0 V		5		nC
Gate to Drain Charge	Qgd	ID = 32 A		9		nC
Body Diode Forward Voltage Note	VF(S-D)	IF = 32 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 32 A, VGS = 0 V		41		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		58		nC

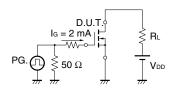
Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

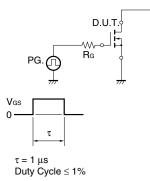


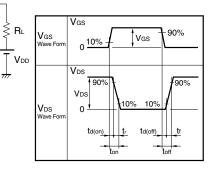


TEST CIRCUIT 3 GATE CHARGE



TEST CIRCUIT 2 SWITCHING TIME





TYPICAL CHARACTERISTICS ($T_A = 25^{\circ}C$)

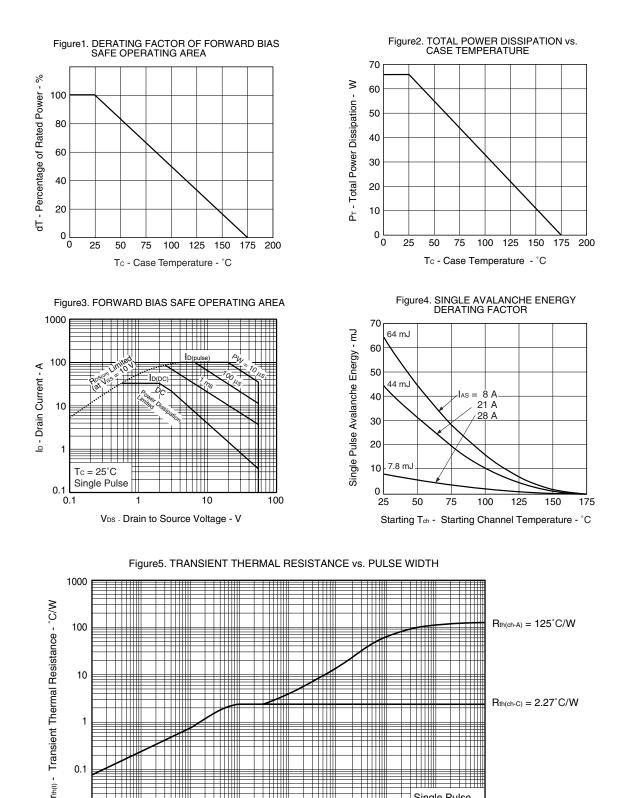
0.1

0.01 10 µ

100 *µ*

1 m

NEC



1

100 m

PW - Pulse Width - s

10 m

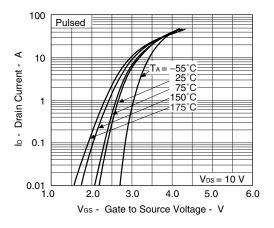
Single Pulse Tc = 25°C

1000

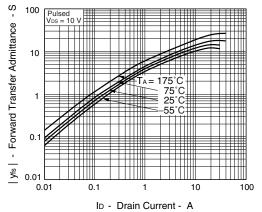
100

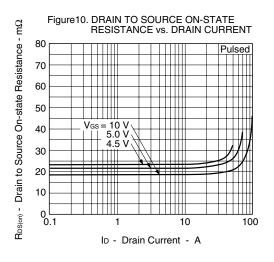
10

Figure6. FORWARD TRANSFER CHARACTERISTICS









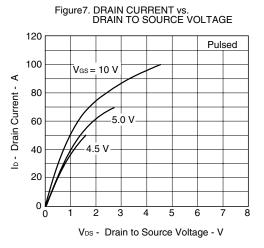


Figure9. DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

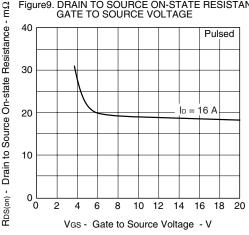
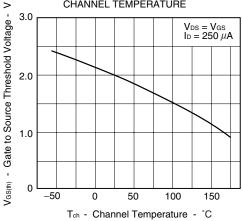
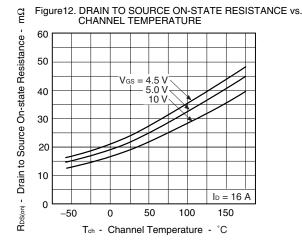
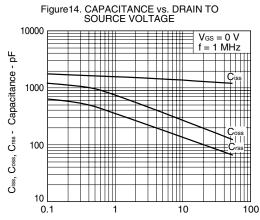


Figure11. GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE









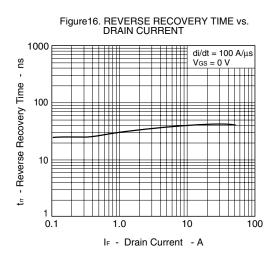


Figure 13. SOURCE TO DRAIN DIODE FORWARD VOLTAGE

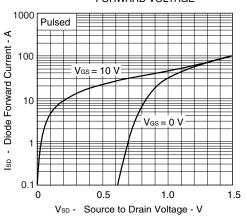


Figure 15. SWITCHING CHARACTERISTICS

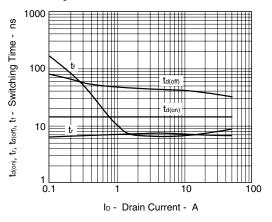
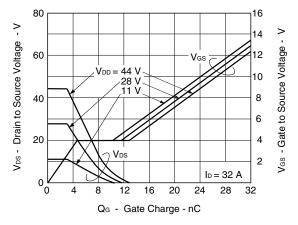
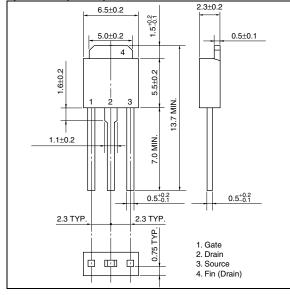


Figure17. DYNAMIC INPUT/OUTPUT CHARACTERISTICS

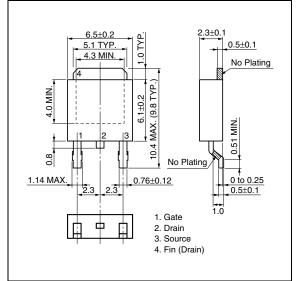


★ PACKAGE DRAWINGS (Unit: mm)

1) TO-251 (JEITA) / MP-3

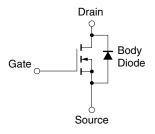


3) TO-252 (JEDEC) / MP-3ZK



2) TO-252 (JEITA) / MP-3Z 6.5±0.2 2.3±0.2 1.5+0.2 5.0±0.2 0.5±0.1 4 4.3 MAX 5.5±0.2 1.0 MIN. 1.8 TYP. 10.0 MAX 1 з 2.0 MIN. . Έ F 1.1±0.2 0.9 MAX. 0.8 MAX 0.7 TYP. . 8.0 2.3 TYP 2.3 TYP. 0.8 TYP. 1. Gate 2. Drain 3. Source 4. Fin (Drain)

EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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